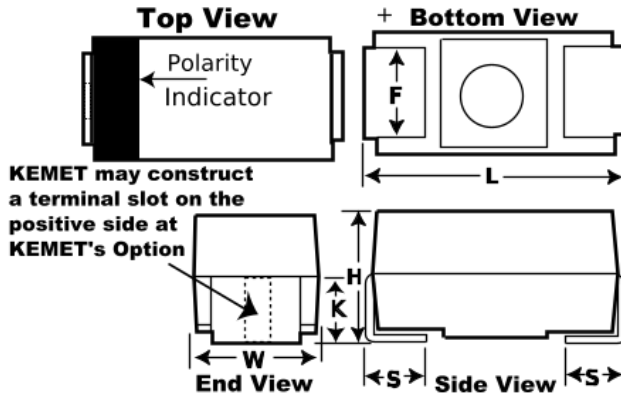


## T498D157K006ZTE500

Obsolete

B45196P, Tantalum, MnO<sub>2</sub> Tantalum, High Temperature, 150 uF, 10%, 6.3 VDC, SMD, Molded, High Temperature, N/A, 500 mOhms, 7343, Height Max = 3.1mm



General Information	
Series	B45196P
Dielectric	MnO <sub>2</sub> Tantalum
Style	SMD Chip
Description	SMD, Molded, High Temperature
Features	High Temperature, Automotive
RoHS	Yes
Termination	Tin
Qualifications	AEC-Q200
AEC-Q200	Yes
Notes	Obsolete.

Dimensions	
Footprint	7343
L	7.3mm +/-0.3mm
W	4.3mm +/-0.3mm
H	2.8mm +/-0.3mm
S	1.3mm +/-0.3mm
F	2.4mm +/-0.1mm
K	1.8mm TYP

Specifications	
Capacitance	150 uF
Capacitance Tolerance	10%
Voltage DC	6.3 VDC (85C), 5.02 VDC (125C), 4.22 VDC (150C)
Temperature Range	-55/+150°C
Rated Temperature	85°C
Dissipation Factor	6%
Failure Rate	N/A
Resistance	0.5 Ohms (100kHz)
Ripple Current	547.7 mAmps (25C), 492.9 mAmps (85C), 219.1 mAmps (125C)
Leakage Current	9.5 uA

Packaging Specifications	
Packaging	T&R, 178mm
Packaging Quantity	750

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